



PRODUCT NAME : BTA41-600 40A 600V T
RIAC

PRICE : Rs 199.00

SKU : RM2014



DESCRIPTION

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Features

- Gate Turn-On Voltage (Vgt): 1.3V
- Peak Off-State Voltage(Vdrm): 600V
- On-State Current (It): 40.0A
- Gate Current (Igt): 50mA
- Av. Gate Power Dissipation (Pg): 1W
- Typical Voltage Change over Time (dV/dT): 500V/μs



BTA40 and BTA/BTB41 Series

STANDARD

40A TRIACs

MAIN FEATURES:

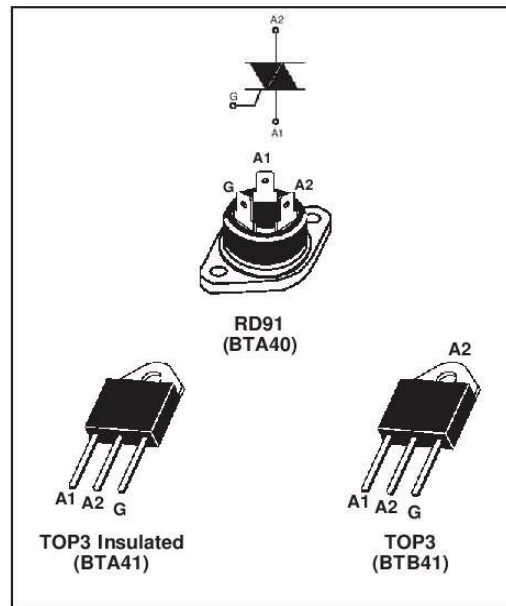
Symbol	Value	Unit
$I_{T(RMS)}$	40	A
V_{DRM}/V_{RRM}	600 and 800	V
$I_{GT} (Q_1)$	50	mA

DESCRIPTION

Available in high power packages, the BTA/BTB40-41 series is suitable for general purpose AC power switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, water heaters, induction motor starting circuits, welding equipment... or for phase control operation in high power motor speed controllers, soft start circuits...

Thanks to their clip assembly technique, they provide a superior performance in surge current handling capabilities.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500 V RMS) complying with UL standards (File ref.: E81734).



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	RD91	40	A
		TOP3		
		TOP3 Ins.		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C)	F = 60 Hz	420	A
		F = 50 Hz	400	A
$I t$	$I t$ Value for fusing	$t_p = 10$ ms	880	A s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100$ ns	F = 120 Hz	50	A/ μ s
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	$t_p = 10$ ms	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20$ μ s	8	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ\text{C}$	1	W
T_{stg}	Storage junction temperature range		- 40 to + 150	°C
T_j	Operating junction temperature range		- 40 to + 125	

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BTA40 and BTA/BTB41 Series

ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

Symbol	Test Conditions	Quadrant		Value	Unit
I _{GT} (1)	V _D = 12 V R _L = 33 Ω	I - II - III IV	MAX.	50 100	mA
V _{GT}		ALL	MAX.	1.3	V
V _{GD}	V _D = V _{DRM} R _L = 3.3 kΩ T _J = 125°C	ALL	MIN.	0.2	V
I _H (2)	I _T = 500 mA		MAX.	80	mA
I _L	I _G = 1.2 I _{GT}	I - III - IV	MAX.	70	mA
		II		160	
dV/dt (2)	V _D = 67 % V _{DRM} gate open T _J = 125°C		MIN.	500	V/μs
(dV/dt) _c (2)	(dI/dt) _c = 20 A/ms T _J = 125°C		MIN.	10	V/μs

STATIC CHARACTERISTICS

Symbol	Test Conditions		Value	Unit	
V _{TM} (2)	I _{TM} = 60 A tp = 380 μs	T _J = 25°C	MAX.	1.55	V
V _{IO} (2)	Threshold voltage	T _J = 125°C	MAX.	0.85	V
R _d (2)	Dynamic resistance	T _J = 125°C	MAX.	10	mΩ
I _{DRM} I _{RDM}	V _{DRM} = V _{RDM}	T _J = 25°C	MAX.	5	μA
		T _J = 125°C		5	mA

Note 1: minimum IGT is guaranteed at 5% of IGT max.

Note 2: for both polarities of A2 referenced to A1

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R _{th(j-c)}	Junction to case (AC)	RD91 (Insulated) TOP3	0.9	°C/W
		TOP3 Insulated	1.2	
R _{th(j-a)}	Junction to ambient	TOP3	50	°C/W
		TOP3 Insulated		

PRODUCT SELECTOR

Part Number	Voltage (xxx)		Sensitivity	Type	Package
	600 V	800 V			
BTA40-xxxB	X	X	50 mA	Standard	RD91
BTA/BTB41-xxxB	X	X	50 mA	Standard	TOP3

BTB: Non insulated TOP3 package



